

淡江大學 101 學年度進修學士班轉學生招生考試試題

系別：電機工程學系三年級

科目：電子學

考試日期：7月18日(星期三) 第3節

本試題共 5 大題， 2 頁

1. 20% The diode shown in Fig. 1 is with $I_S = 2 \times 10^{-15}$ A. Calculate V_{D1} and I_X for $V_X = 0.7V$ and $1.5V$, respectively.

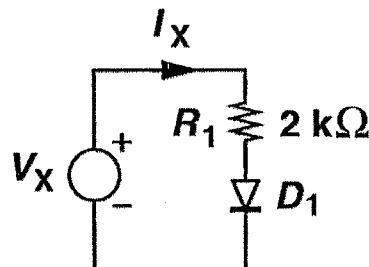


Fig. 1

2. 20% Assuming $V_{in} = V_p \sin \omega t$, plot the output wave form of the circuit shown in Fig. 2 for an initial condition of +0.5V across C_1 . Assume $V_p = 5V$.

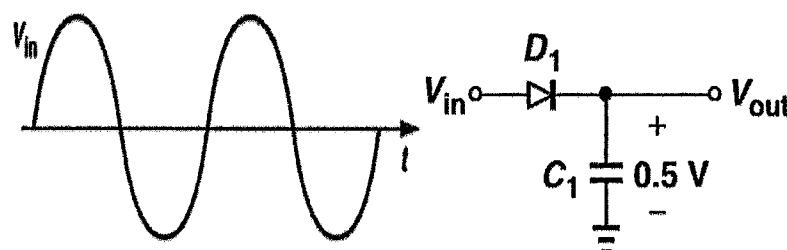


Fig. 2

3. 20% Calculate V_X in Fig. 3 if $I_S = 2 \times 10^{-16}$ A.

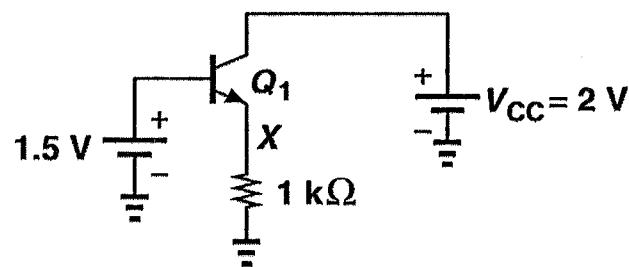
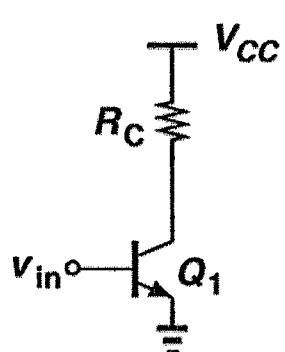
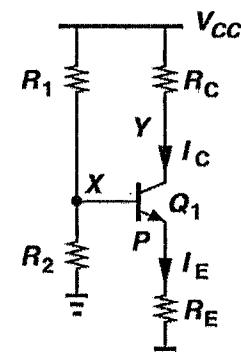


Fig. 3

4. 20% Draw the small signal circuit by using hybrid- π model for the following BJT circuits.



(a)



(b)

Fig. 4

本試題雙面印刷

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5. 20% Calculate v_{out}/v_{in} for the circuit shown in Fig. 5. Assume $I_S = 8 \times 10^{-16} A$, $\beta = 100$, and $V_A = \infty$.
Also assume the capacitors are very large.

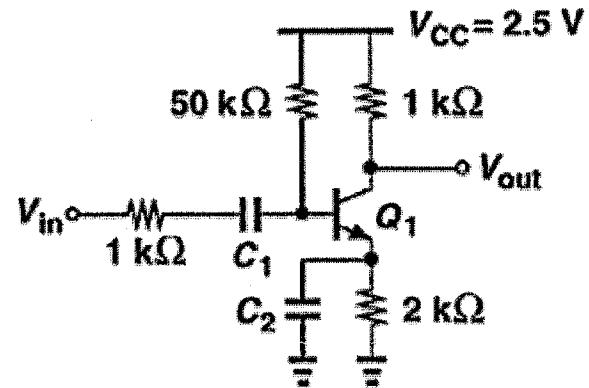


Fig. 5